## NSN 5961-01-005-0362

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-005-0362 **Inclosure Material:** Ceramic **Overall Length:** Between 1.020 inches and 1.060 inches **Overall Diameter:** 2.100 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 reverse voltage, peak **Current Rating Per Characteristic:** 500.00 milliamperes forward current, total rms peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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